Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 0.170 inches	and 0.210 inches
Terminal Length:	
Between 0.500 inches	and 0.750 inches
Overall Diameter:	
Between 0.209 inches	and 0.230 inches
	ice Engineering Council/jedec/case Outline Designation:
To-18	
	electrically Connected To Case:
Anode	
Mounting Method:	
Terminal	
Terminal Circle Diam	eter:
0.100 inches	
Features Provided:	
Hermetically sealed ca	ase
Semiconductor Mate	
Silicon	
	Its Per Characteristic:
	peak and 0.6 gate trigger voltage, dc
Current Rating Per C	
_	prward current, average absolute and 20.00 microamperes gate trigger current, dc
Maximum Operating	Tempurature Per Measurement Point:
150.0 degrees celsius	ambient air
Precious Material An	d Location:
Terminal surface optic	n gold
Test Data Document	
81349-mil-s-19500 sp	ecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes com	mercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and pe	rformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And G	luantity:
3 uninsulated wire lea	d
Specification Data:	
81349-mil-s-19500/41	9 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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